



Magnetic Order and Muon Diffusion in VO₂

Rick Mengyan, Ph.D.

*Research Associate
Texas Tech University, Physics
Lubbock, TX 79409-1051 USA*

Collaboration:

R.L. Lichti, B.B. Baker, G. Jayarathna
Texas Tech

Support:

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Experimental Facility:

ISIS: EMU
TRIUMF:
M15 - HiTime
M20 - Helios



Basic Properties of VO₂

Transitions

- Reversible, Metal-Semiconducting at T_{MST} = 340 K
- Structural: Rutile (T > T_{MST}) → Monoclinic (M1, T < T_{MST})

	Metallic	Semiconducting
Band Gap	~0 eV	~1 eV
Optical Property	Reflective (Near IR)	Translucent
Conductivity	~10 ³ -10 ⁴ (Ωcm) ⁻¹	~10 ⁻¹ -10 ⁻³ (Ωcm) ⁻¹

Triggered by:

- Temperature, E-field, Optical Excitation, Pressure

Potential Applications

- Microwave wave guides, smart-windows, reconfigurable and switchable antennae, ultra-fast optical filters

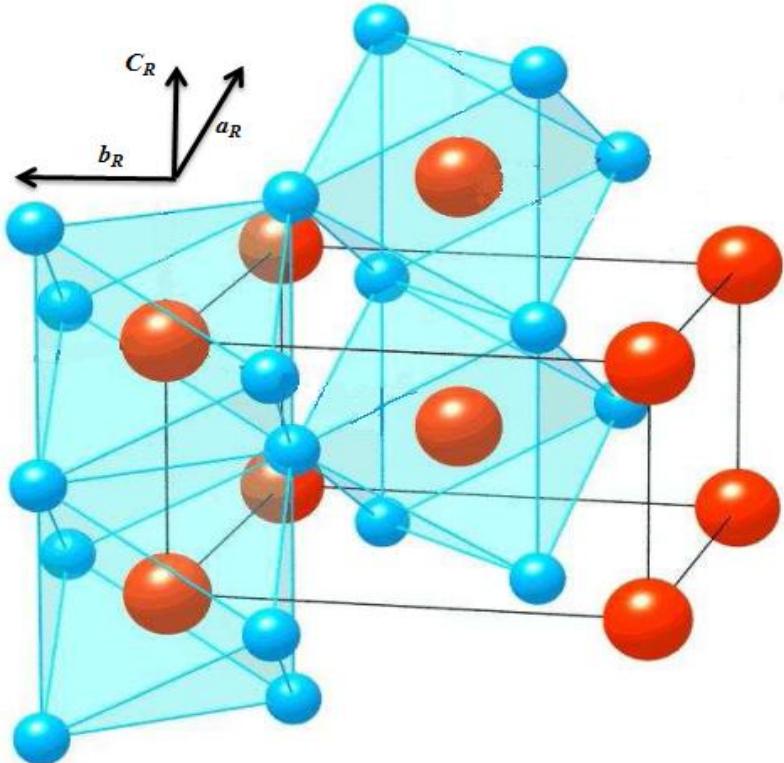
F. J. Morin, *Phys. Rev. Lett.* **3** (1959) 34; A. Cavalleri *et al*, *J. Phys Soc Japan* **75** (2006) 011004

B. J. Kim, *et al* *Appl Phys Lett* **90** (2007) 023515; M. M. Qazilbash, *et al* *Appl Phys Lett* **92** (2008) 241906

M. Imada, *et al* *Rev Mod Phys* **70** (1998) 1039; J. B. Goodenough, *J. Solid State Chem.* **3** (1971) 490



Structure: Metallic ($T > T_{MST}$)

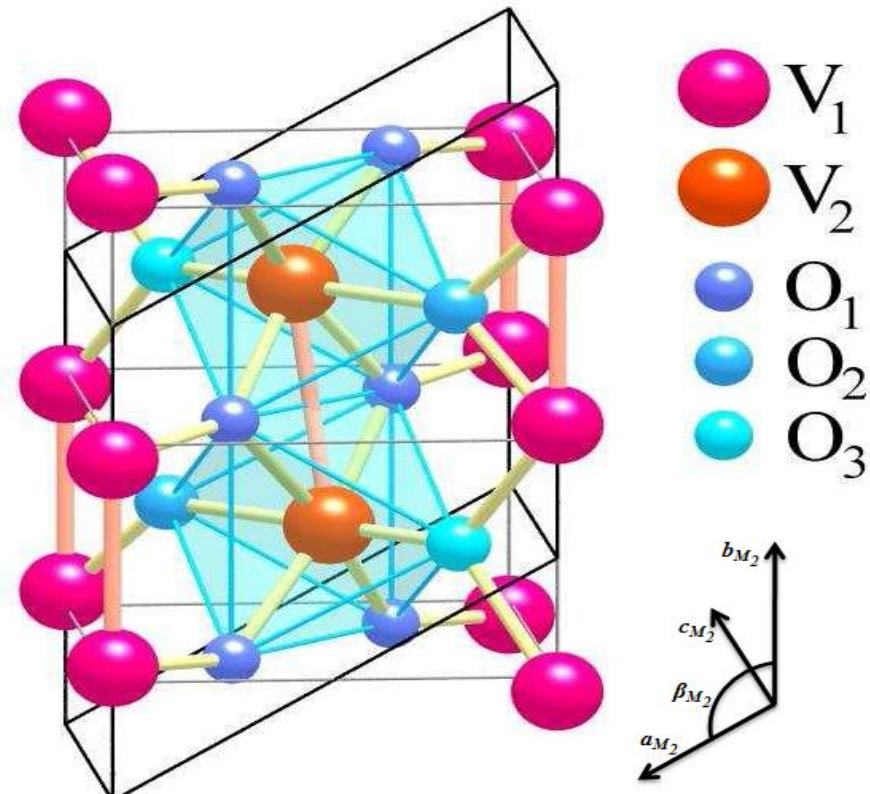


- Tetragonal body-centered unit cell
- V surrounded by octahedron of O atoms
- V^{4+} has single e^- near Fermi level, occupies lowest $3d$ level
- Asymmetry in crystal field splits $3d$ states with lowest orbital aligned along c-axis (\rightarrow higher conductivity)



Structure: Semiconducting ($T < T_{MST}$)

- V–V dimerization → doubled unit cell
- V atoms pair along *c*-axis
- One V per pair:
 - Shift in *a*–*b* plane
 - Closer to partner along *c*
- Dimerization pairs e[−] into singlet state, lead to
 - High resistivity
 - Non-zero bandgap



Semiconducting (Monoclinic)
Pink V₁ paired with twisting
Orange V₂ paired without twisting



Background

H investigated as a dopant (~0 to 3.8% H)

- Nominal resistivity change; remains metallic down to 200 K (at 3.8% H)
- Effect has been observed but role H *actually* plays needs investigation [C. Wu, et al. *J. Am. Chem. Soc.* **133** (2011) 13798]

Dopants introduced, modify transition temperature

- W, Ti, Au: Lower transition temperature
- Cr, Al: Raise transition temperature
- **Minimal effects** on properties other than T_{MST}
- *Actual* role dopants play needs additional thorough investigation
[ie: P. Kiri, et al. *Adv Mat Lett* **1** (2010) 86; Burkhardt, et al. *Thin Solid Films* **345** (1999) 229; A. Kaye, *private communication*, Texas Tech University (May 2013); C. Tang, et al. *Phys Rev B* **31** (1985) 1000]

Applications require exposure to H

- Long-term effects of H has not been studied
- Intentional H incorporation into VO_2 has major effect on transition
→ Important to understand:
 - *How H may propagate into & Behavior in bulk VO_2*



Project Focus: VO₂ Compounds

- General study of Mu in VO₂
ie: Unique contribution to H defect studies (early time)
 - Stability, Charge & Site dynamics, Energy Barriers, Diffusion Parameters, etc
- Local environment of VO₂ [vs VO₂:X]
 - Role dopants play in modifying various phases and transition
 - Sensitive magnetic probe:
Dimer $S_{net} = 0$
Magnetic moments introduced by disruption of V-V dimerization
- Local probe of yet to be understood transition
 - Mechanism (Mott-Hubbard vs Peierls)
 - Role Dopants play (c.f. Modification of environment, etc)



Experiment Details

ZF-MuSR

EMU (ISIS), HiTime and
Helios (TRIUMF)

- Mu diffusion 8 K to 560 K
- Dynamics (field fluctuations or mu motion)
- Local magnetic environment

wTF-MuSR

EMU, $B_{TF} = 100G$

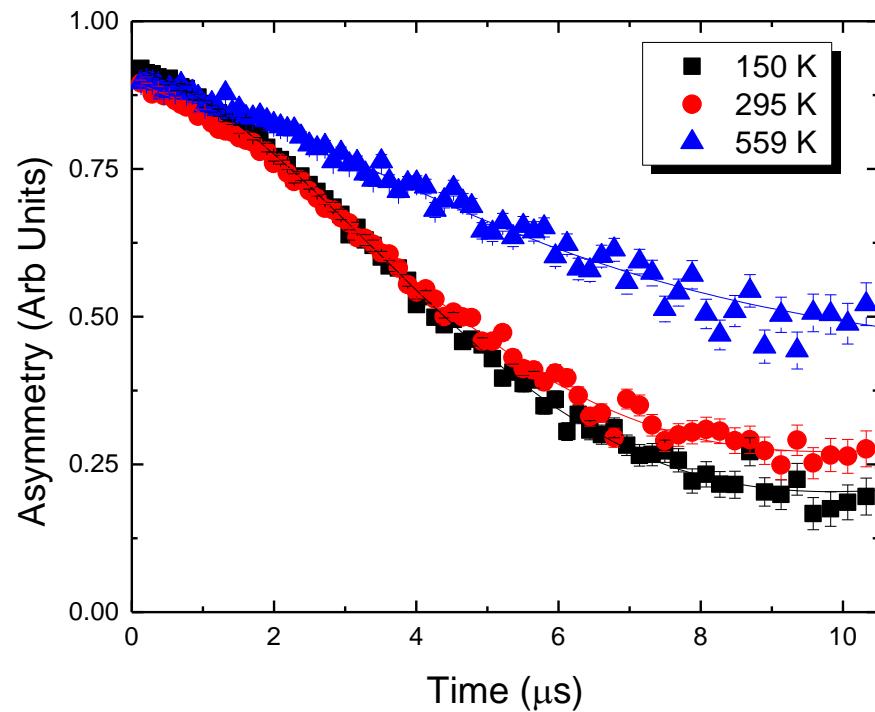
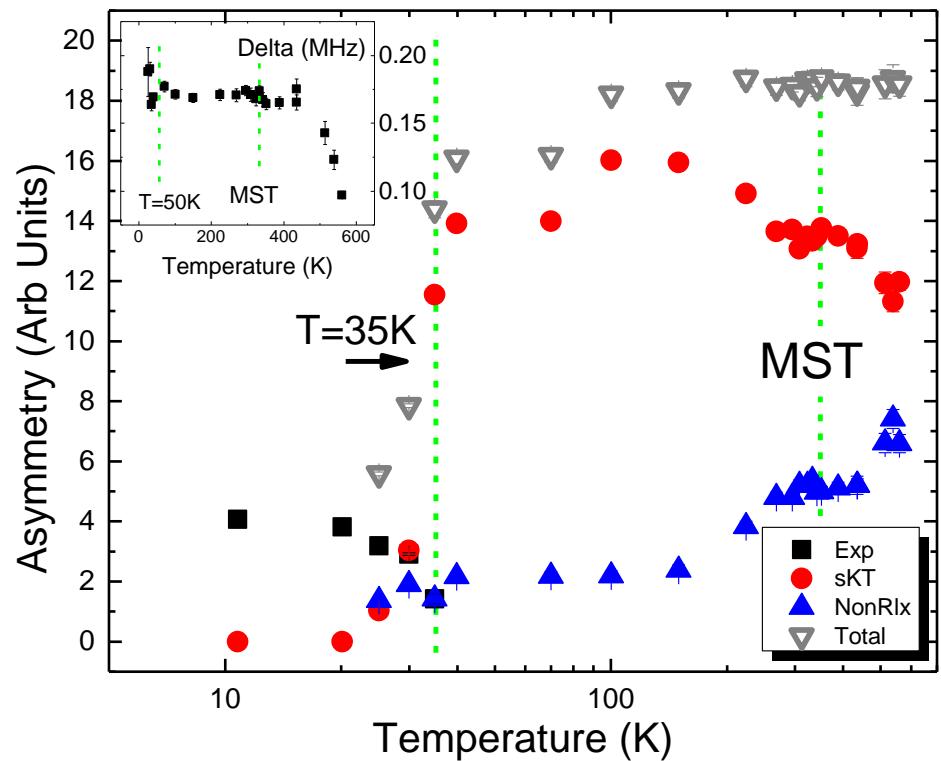
- ZF α calibration
- Basic character info

HTF-MuSR

- HiTime, B_{ext} up to 6.5 T
- Identify & characterize sites
- Investigate Mu^0/Mu^0 -like states & formation
- Characterize magnetism



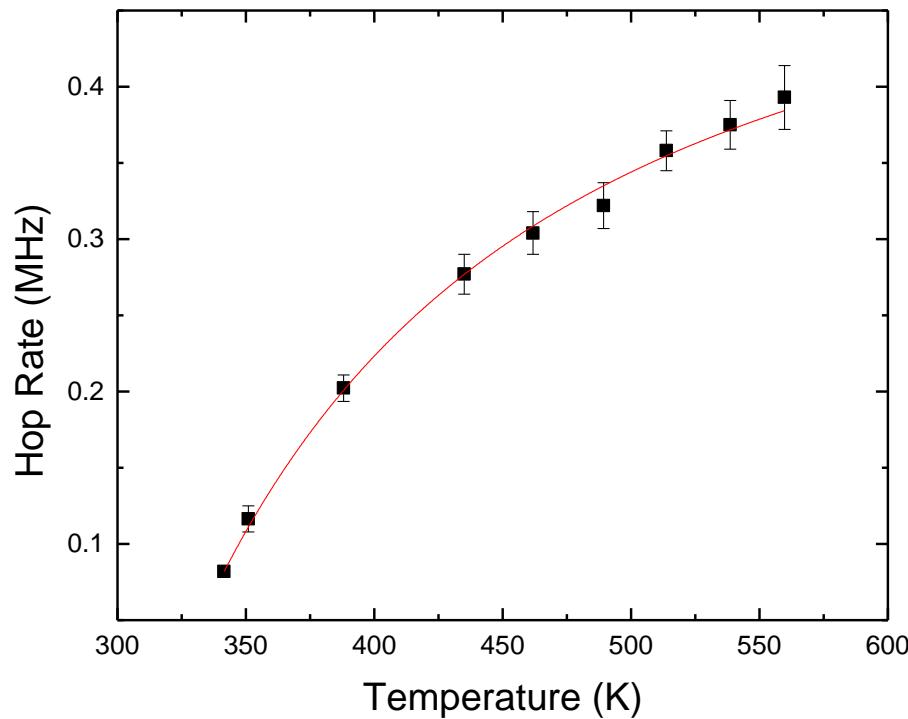
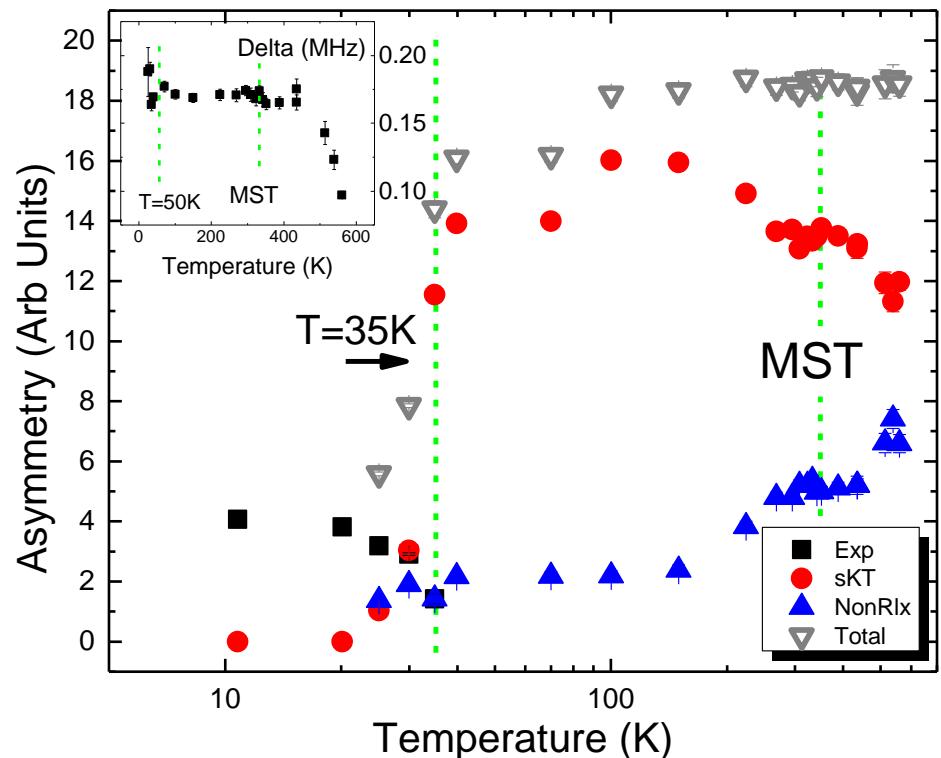
Results and Discussion



- 1) Static between 100 K and \sim 300 K
 $\Delta = 0.171 \pm 0.004$ MHz
- 2) Detect change in mu site around MST
 $\Delta(T > T_{MST}) = 0.165 \pm 0.005$ MHz



Results and Discussion

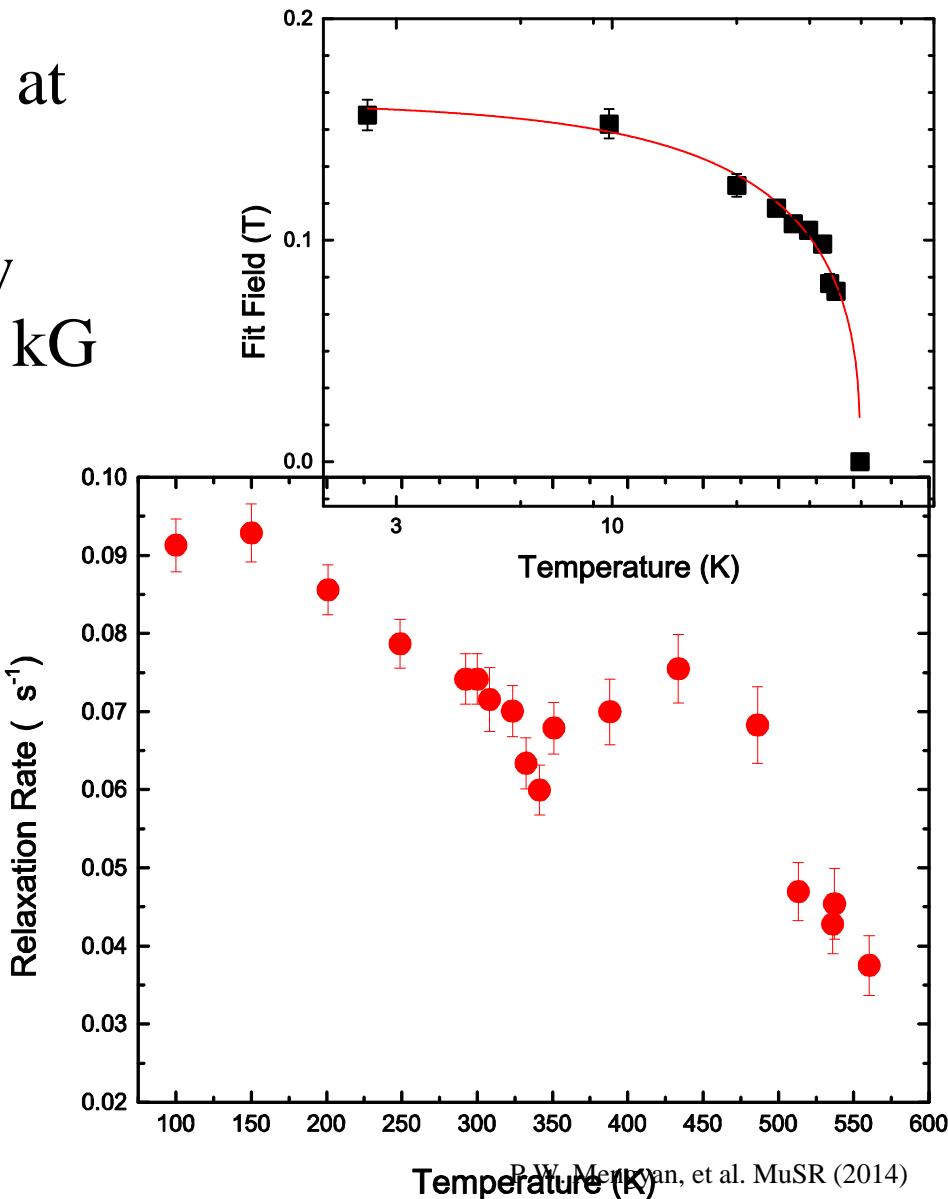
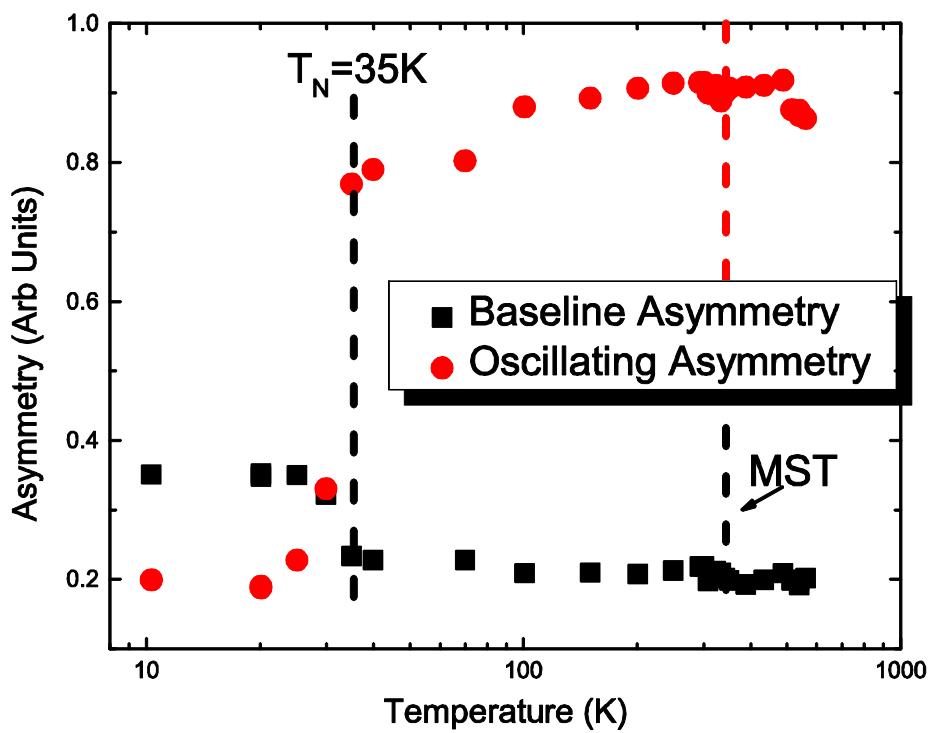


- 3) Dynamic at higher T, fit down to $\sim 340\text{ K}$
- 4) $T < 35\text{ K}$, trade off in Asy; $B_{\text{loc},\text{max}} = 0.62 \pm 0.08\text{ kG}$
- 5) Small fraction fits to same B_{loc} between $35\text{ K} & 100\text{ K}$ suggesting small fraction of high local order starting $\sim 100\text{ K}$

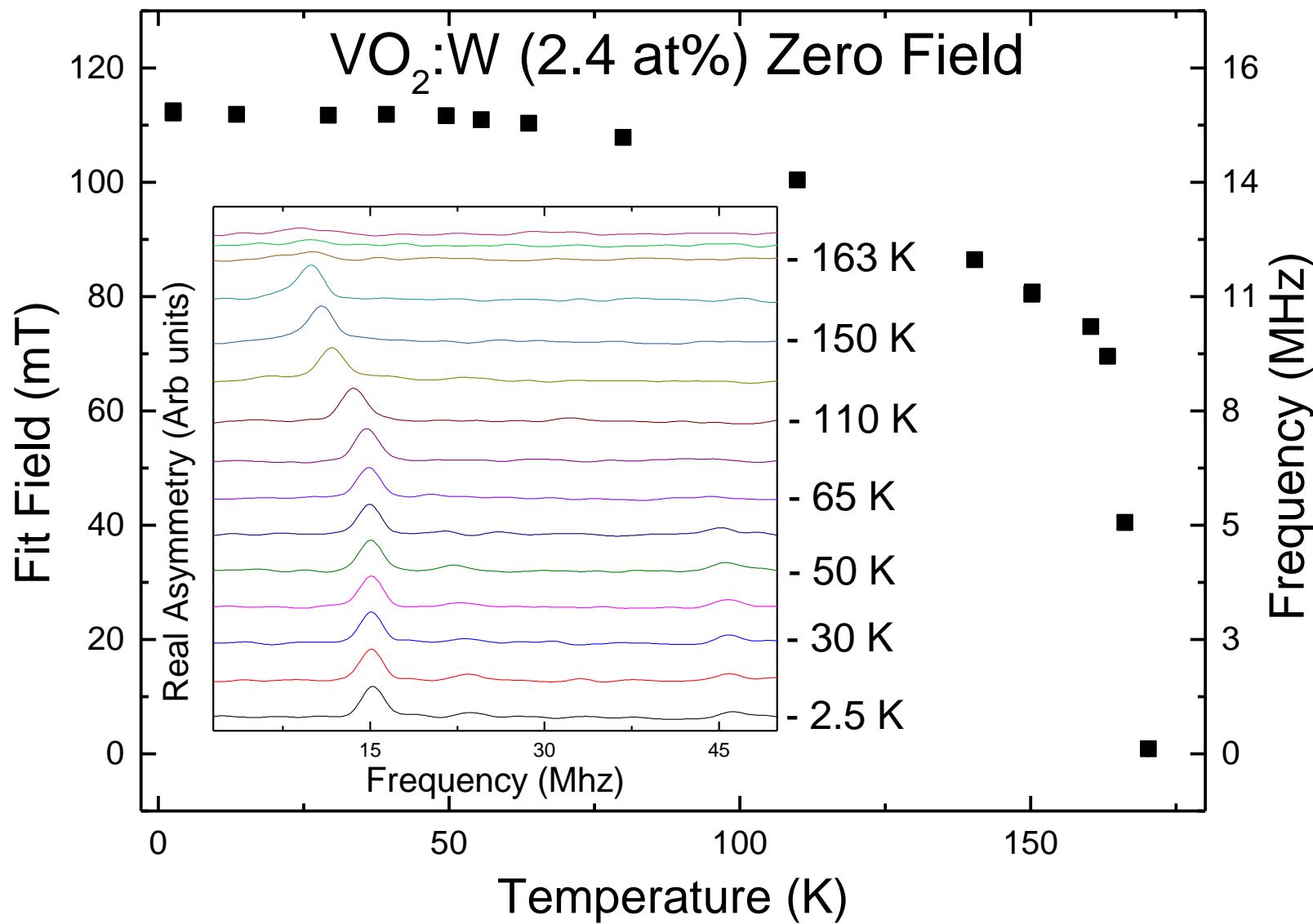


Results and Discussion

- 6) TF show relaxation features at 340 and near 450 K
- 7) Fit field – critical power law
 $B_{loc} = B_{loc,max} = 0.62 \pm 0.08 \text{ kG}$



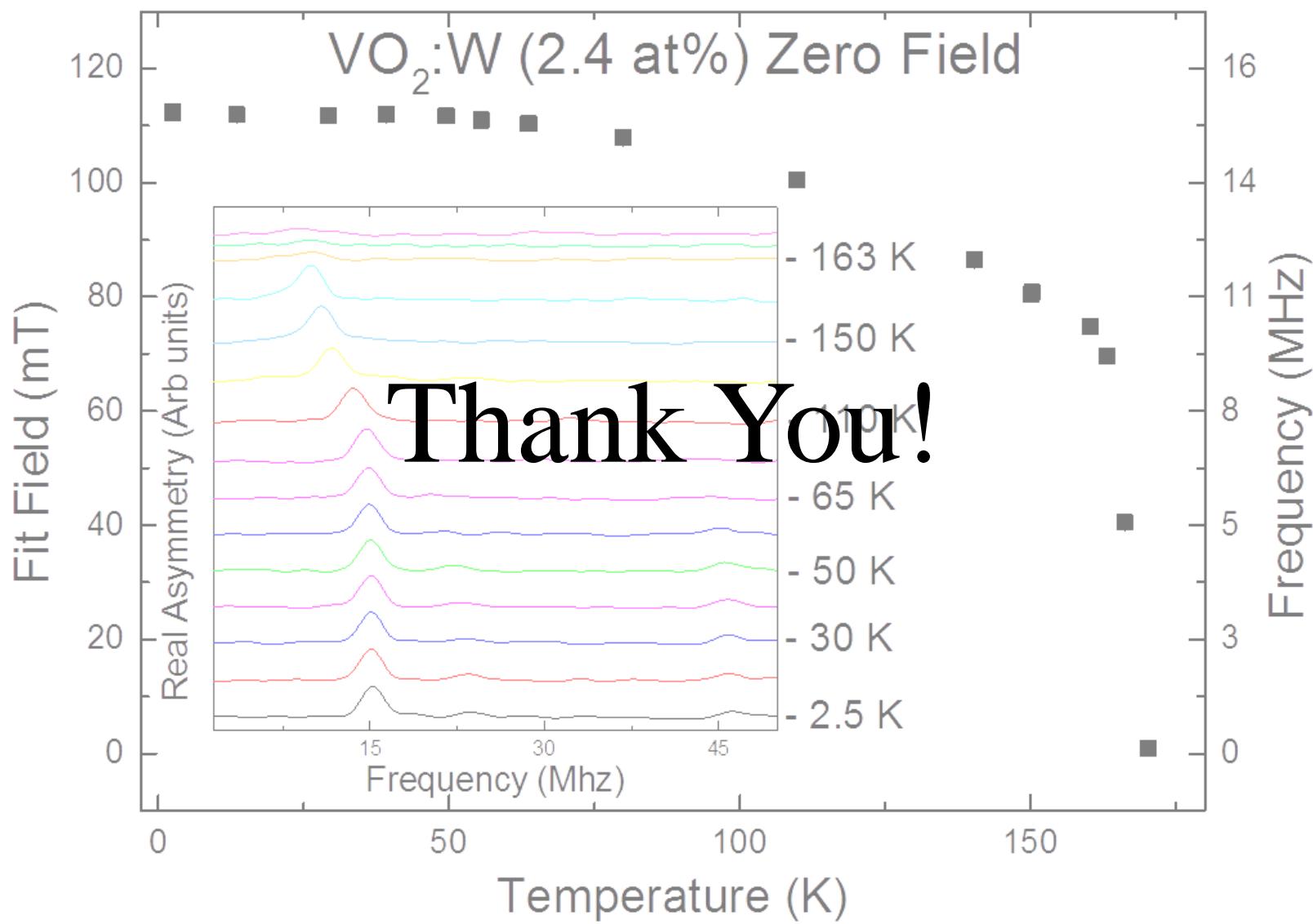
ZF-MuSR: VO₂:W (97.6:2.4 at%)





Summary

- Mu is sensitive to a feature near the MST and low temperature magnetism
- $T < 35$ K Magnetic phase $B_{loc} = 0.62 \pm 0.08$ kG in VO_2
- 35 K to ~ 100 K localized magnetic features
- Static between 100 K – 300 K
- Significant dynamics above 450K;
possibly starting near 340K -- just above MST
- 5 at% Ti & 2.4 at % W show $T_c \sim 175$ K with
 $B_{loc} \sim 1.1$ kG





Thank you



Transition Mechanism Question

- Basic properties of stoichiometric VO_2 well into each phase are well understood
- Driving mechanism of transition highly debated
 - *(1) instability in Fermi surface caused by periodic lattice deformations (V-V pairing) which causes an energy gap to open (Peiels Mechanism)*

OR

- *(2) is it related to strong $e^- - e^-$ correlations that introduce an energy gap from the mutual repulsion (Mott-Hubbard mechanism)*
- Understanding of this transition is required for better control and optimization of the properties for any application



Goals with MuSR

Use μ^+ as experimentally accessible analog to hydrogen

- Probe Mu^0/H like states
- Mu/H diffusion

Mu as sensitive local probe to investigate local magnetic environment

- Through transition
- Well into each phase



Experimentally Accessible Analog to Hydrogen

	Muon	Proton
Mass (m_p)	$0.1126 \approx 1/9$	1
Spin	$1/2$	$1/2$
Gyro. Ratio, γ ($s^{-1} T^{-1}$)	8.51607×10^8 $\approx 3.2 \times \gamma_P$	2.67520×10^8
Lifetime, τ (μs)	2.19709	Stable
	Muonium	Hydrogen
Red. e^- mass (m_e)	0.995187	0.999456
G. S. Radius (\AA)	0.531736	0.529465
G. S. Energy (eV)	-13.5403	-13.5984

Muonium ($\text{Mu} \equiv \mu^+ e^-$)

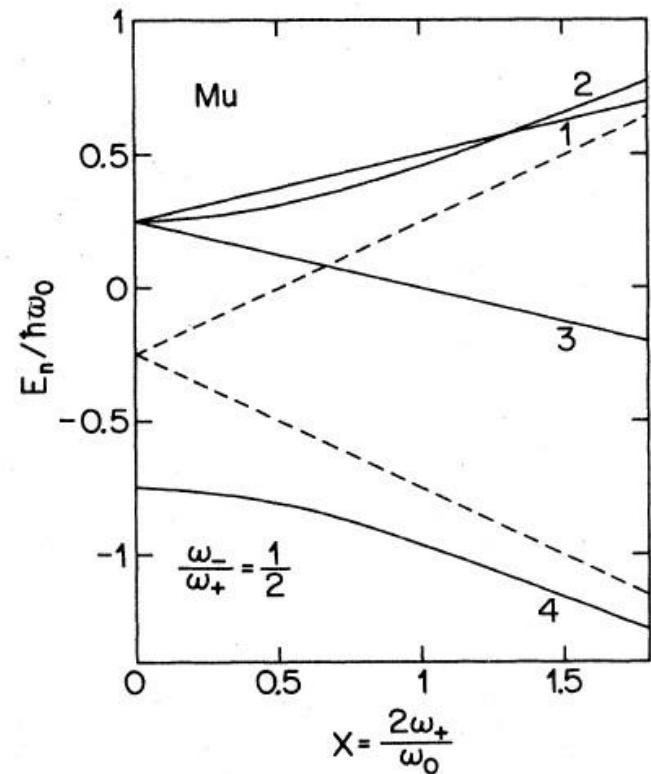
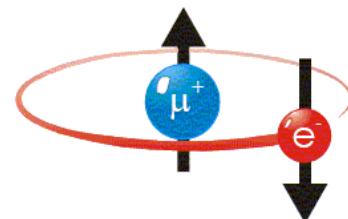
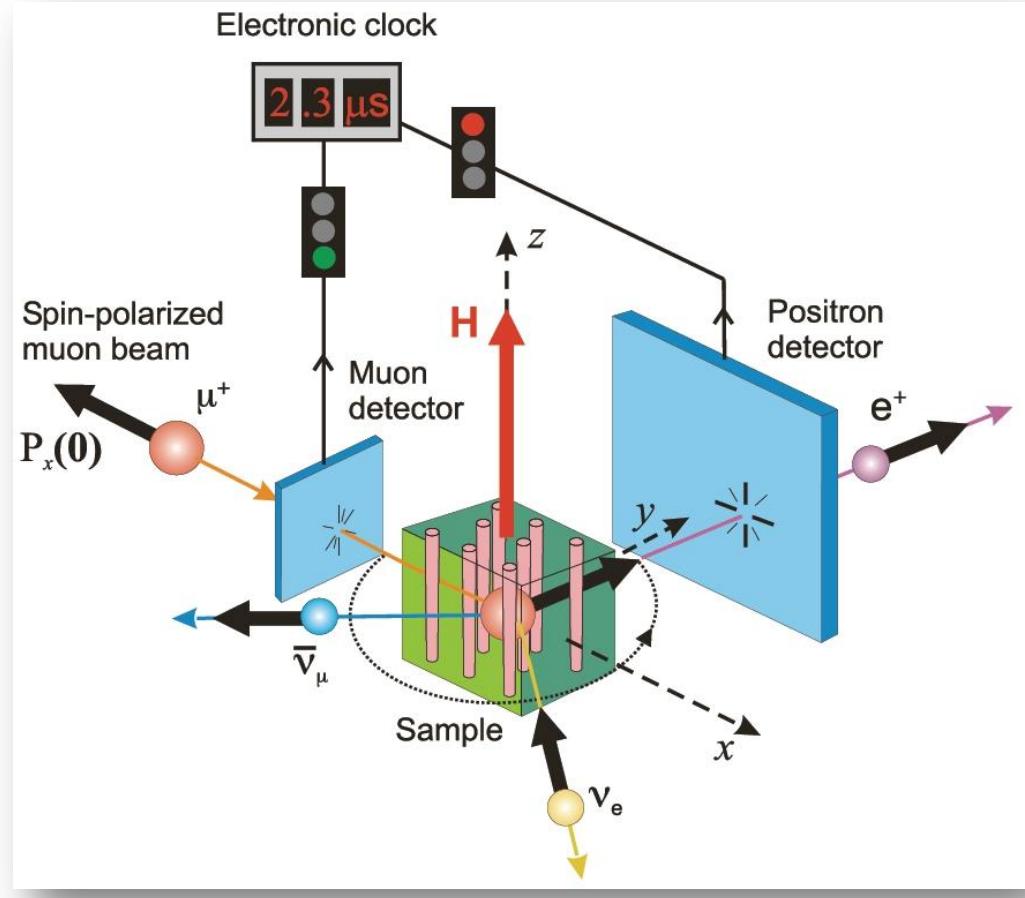


FIG. 1. The hyperfine energy-level (Breit-Rabi) diagram for isotropic 1s-Mu as a function of the dimensionless magnetic field $x = B(g_\mu\mu_\mu - g_e\mu_B)/(\hbar A)$. A fictitious value for the quantity ω_-/ω_+ has been used for clarity; its true value is 0.9904. The dashed lines are the high-field asymptotes for levels 2 and 4.



TF- μ SR



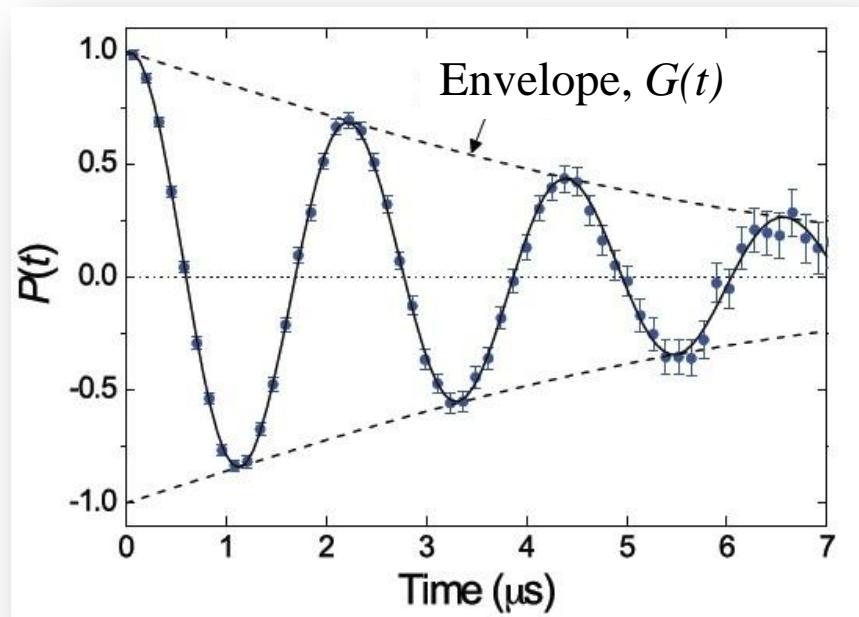
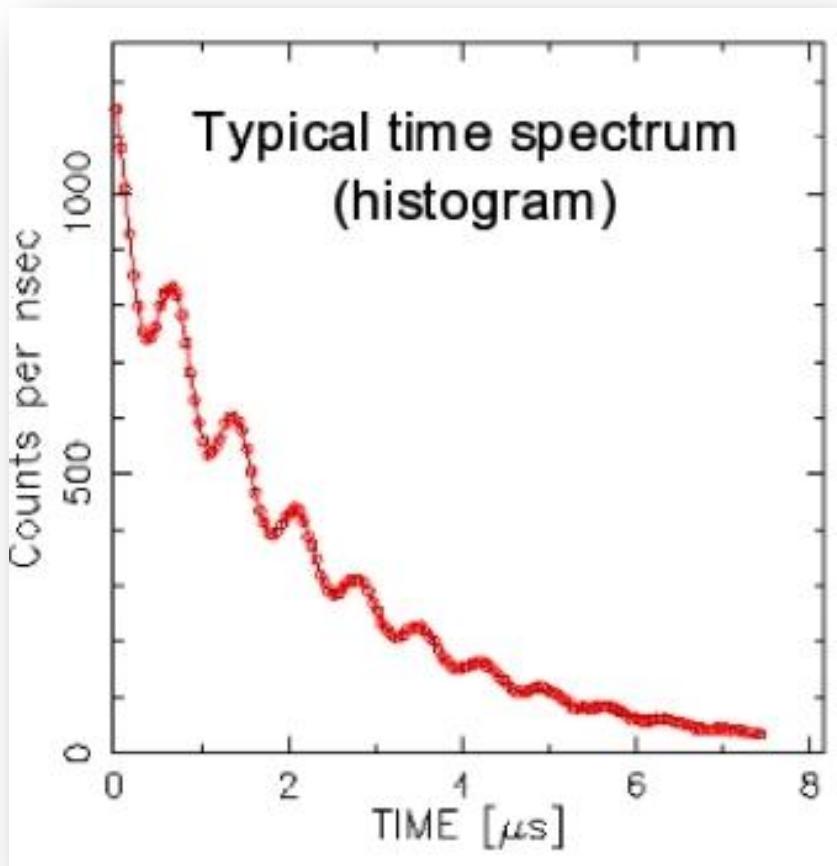
Field applied \perp to initial spin polarization
→ μ^+ spin precession about applied field at:

$$v_{\mu+} = \gamma_\mu \times |\mathbf{B}| \quad |\gamma_\mu| = 135.54 \text{ MHz/T}$$

$Mu^0 = \mu^+ + e^-$
→ spin-orbit coupling
→ affects local field of μ^+
→ diff prec. Freq for:
 $|\uparrow_\mu\rangle + |\uparrow_e\rangle$ & $|\uparrow_\mu\rangle + |\downarrow_e\rangle$



TF- μ SR: Sample signal from relaxing μ^+



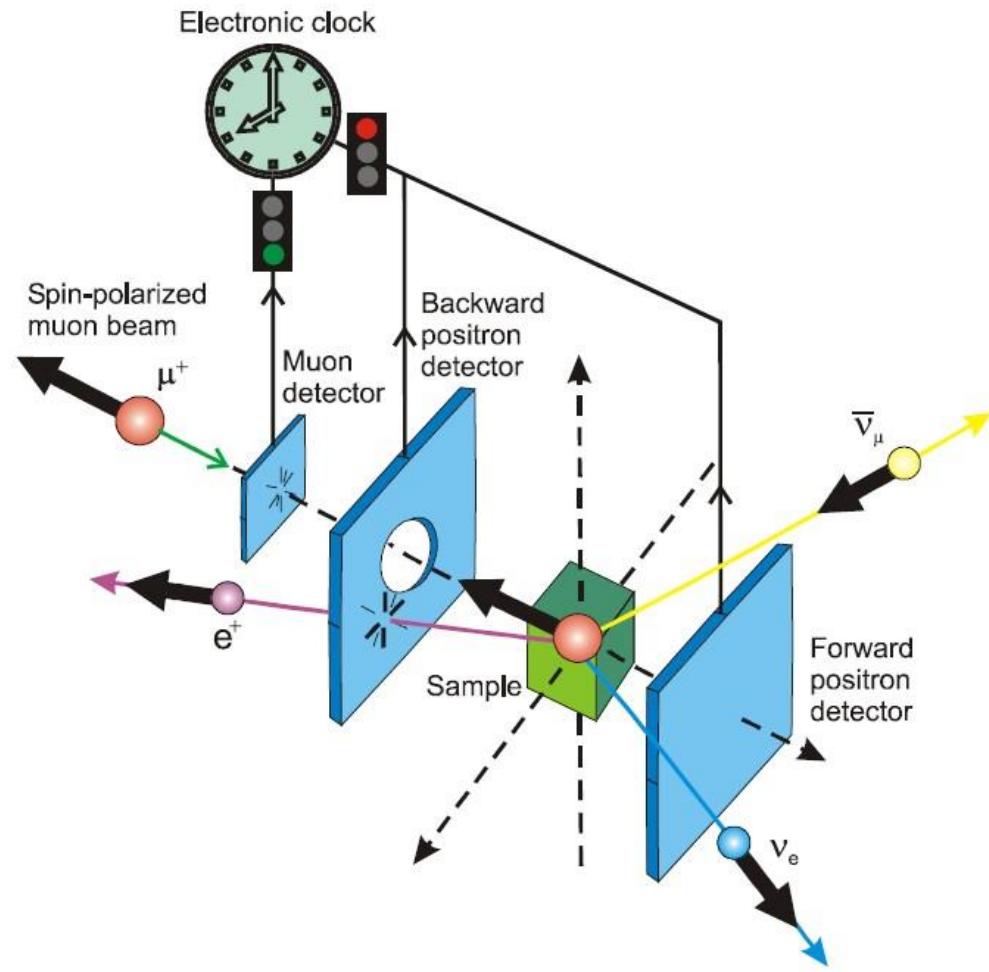
$$P(t) = G(t) \cos\left(\gamma_{\mu^+} |\mathbf{B}_{\mu^+}| + \delta\right)$$



LF- μ SR

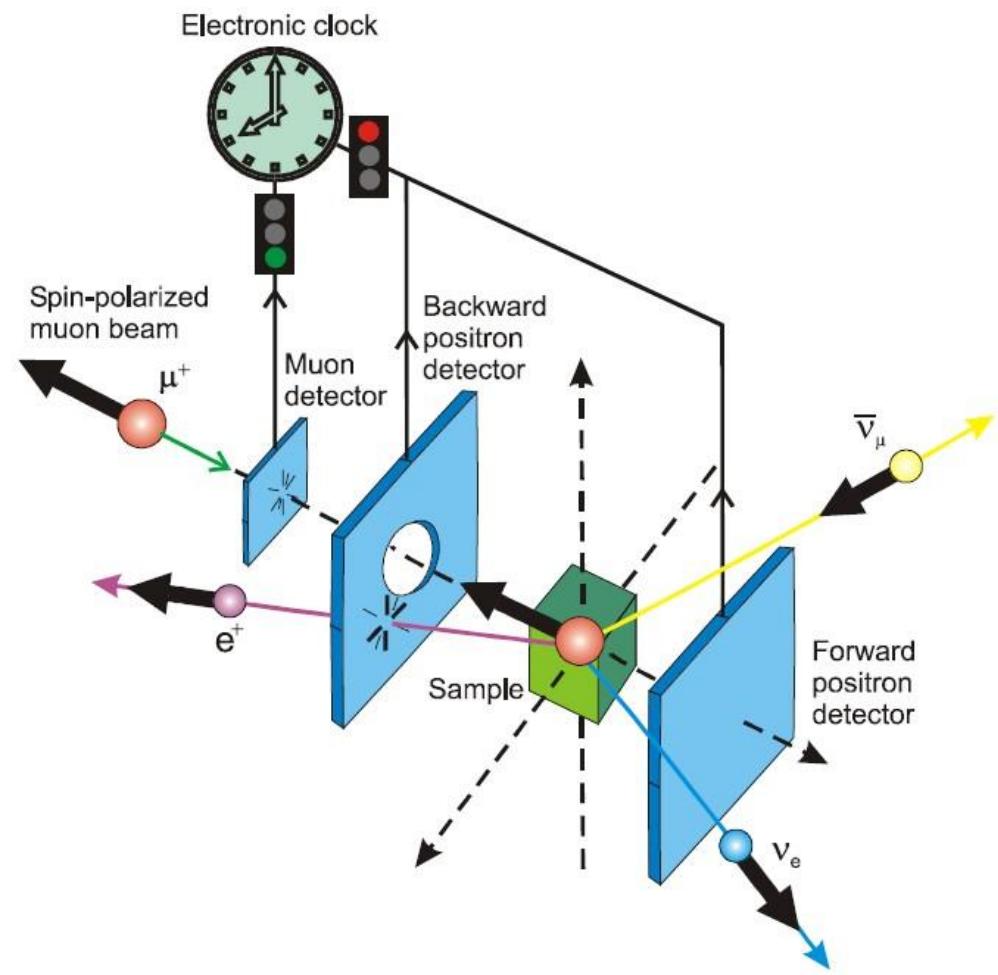
B applied \parallel to μ^+ spin pol.
See time evolution of P(t)
along original direction

=> Change in Spin P(t) from:
1) local environment (nearby
nuclear moments)
2) muonium motion
(e^- spin-flip w/ each site
change, transferring back to
 μ^+ contributing to $\Delta P(t)$)





ZF- μ SR



No net B applied
See time evolution of P(t)
in natural environment

=> Change in Spin P(t)
from:
1) local environment
(nearby nuclear moments)
2) μ^+ motion